TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62008AP,TD62008F,TD62008AF

7CH DARLINGTON SINK DRIVER

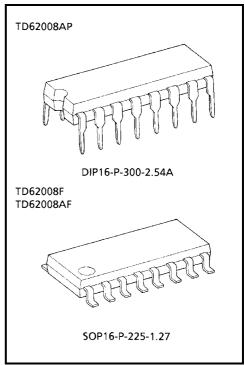
The TD62008AP / F / AF are high–voltage, high–current darlington drivers comprised of seven NPN darlington pairs. All units feature integral clamp diodes for switching inductive loads and protective diodes against a negative input voltage. The TD62008AP / F / AF are suitable for interfaces from minus and plus dual supply voltage system to plus single supply voltage system.

Applications include relay, hammer, lamp and display (LED) drivers.

Please observe the thermal condition for using.

FEATURES

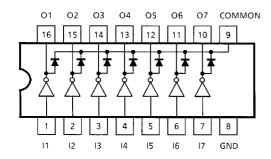
- Output current (single output) 400 mA (Max)
- High sustaining voltage output 50 V (Min)
- Output clamp diodes
- Protective diodes against a negative input voltage
- Inputs base resistor RIN = $20 \text{ k}\Omega$
- Inputs compatible with 9~15 V PMOS, CMOS.
- Package type-AP : DIP-16 pin
 Package type-F, AF: SOP-16 pin



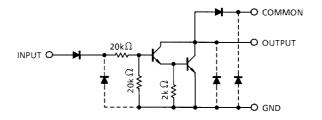
Weight

DIP16-P-300-2.54A: 1.11 g (Typ.) SOP16-P-225-1.27: 0.16 g (Typ.)

PIN CONNECTION (TOP VIEW)



SCHEMATICS (EACH DRIVER)



Note: The input and output parasitic diodes cannot be used as clamp diodes.



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Output Sustaining Voltage	AP / AF	Voc. (OUO)	− 0.5 ~ 50	٧	
	F	V _{CE} (SUS)	-0.5 ~ 35		
Output Current		lout	400	mA / ch	
Input Voltage		V _{IN}	-40 ~ 40	V	
Clamp Diode Reverse Voltage	AP / AF	V_{R}	50	V	
	F	VR	35	V	
Clamp Diode Forward C	urrent	IF	400	mA	
Power Dissipation	AP	D-	1.47	W	
	F/AF	P_{D}	0.625 (Note)	VV	
Operating Temperature		T _{opr}	- 40 ~ 85	°C	
Storage Temperature		T _{stg}	− 55 ~ 150	°C	

Note: On Glass Epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

RECOMMENDED OPERATING CONDITIONS (Ta = -40 \sim 85°C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT	
Output Sustaining Voltage	AP / AF	V (-)		0	_	50	V	
	F	V _{CE} (SUS)		0	_	35	·	
Output Current		I _{OUT}	DC 1 Circuit, T _{pw} = 25%, Duty = 40%	0	_	400	- mA	
			T _{pw} = 25 ms, Duty = 10%, 7 Circuits	0	_	200		
Input Voltage		V _{IN}		-35	_	35	V	
Clamp Diode Reverse Voltage	AP / AF	V _R		_	_	50	V	
	F	٧R		_	_	35	V	
Clamp Diode Forward Current		IF		_	_	400	mA	
Power Dissipation	AP	P_{D}		_	_	0.52	W	
	F/AF		Ta = 85°C (Note)	_	_	0.325	VV	

Note: On Glass Epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

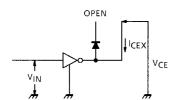


ELECTRICAL CHARACTERISTICS (Ta = 25°C)

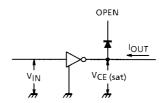
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN	TYP.	MAX	UNIT
Output Leakage Current	AP / AF	losy	1	V _{OUT} = 50 V		_	_	100	μΑ
	F	ICEX		V _{OUT} = 35 V		_	_	100	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	2	I _{OUT} = 400 mA		1	1.3	2.4	V
				I _{OUT} = 200 mA		_	1.0	1.6	
Input Current	"H" Level	I _{IN (ON)}	4	V _{IN} = 18 V		_	0.85	1.8	- mA
				V _{IN} = 35 V		_	_	3.8	
	"L" Level	I _{IN (OFF)}	4	V _{IN} = −35 V		_	_	-20	μΑ
DC Current Transfer Ratio		h _{FE}	3	V _{CE} = 4 V, I _{OUT} = 350 mA		1000	3000	_	
Clamp Diode Reverse Current		I _R	5	V _R = 50 V, V _R = 35 V (Type-F)		_	_	100	μΑ
Clamp Diode Forward Voltage		V _F	6	I _F = 400 mA		_	1.5	2.4	V
Turn-On Delay	AP / AF	+		C _L =	V _{OUT} = 50 V, R _L = 156 Ω	_	0.1	_	μs
	F	t _{ON}	7		V _{OUT} = 35 V, R _L = 110 Ω				
Turn-Off Delay	AP / AF] ′	15 pF	V _{OUT} = 50 V, R _L = 156 Ω		0.2		110	
	F	tOFF			V_{OUT} = 35 V, R_{L} = 110 Ω		0.2		μs

TEST CIRCUIT

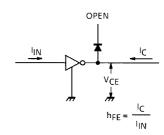
1. ICEX



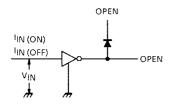
2. VCE (sat)



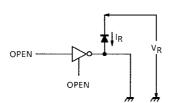
3. hfE



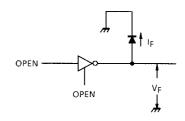
4. I_{IN (ON)}, I_{IN (OFF)}



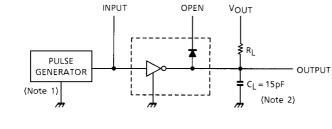
5. I_R

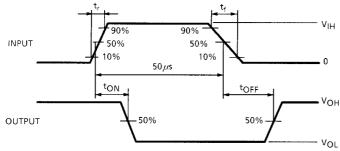


6. V_F



7. ton, toff





Note 1: Pulse Width 50 µs

Duty Cycle 10% Output Impedance 50 Ω

tr ≤ 5 ns, tf ≤ 10 ns

Note 2: CL includes probe and jig capacitance

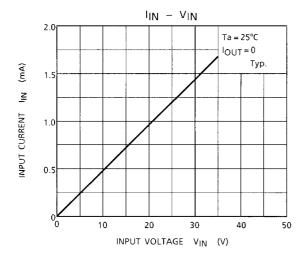
PRECAUTIONS for USING

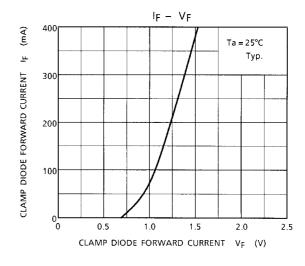
This IC does not include built-in protection circuits for excess current or overvoltage.

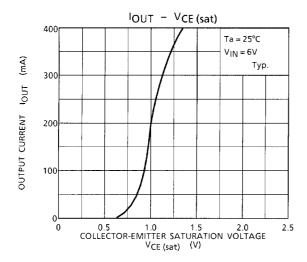
If this IC is subjected to excess current or overvoltage, it may be destroyed.

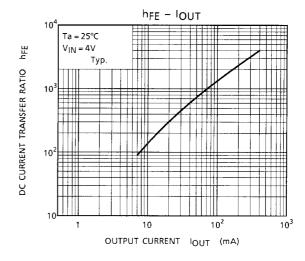
Hence, the utmost care must be taken when systems which incorporate this IC are designed.

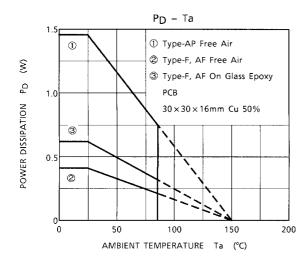
Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

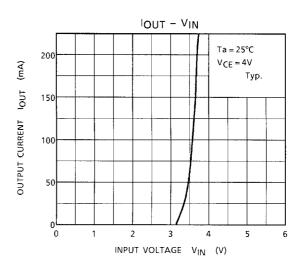






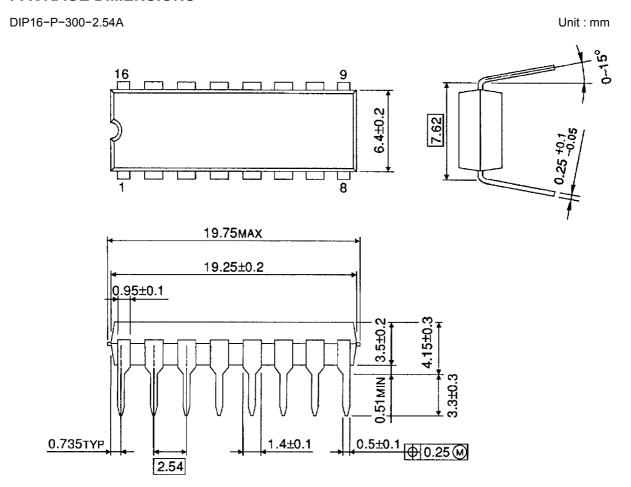






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PACKAGE DIMENSIONS



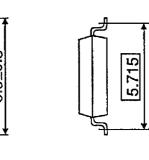
6

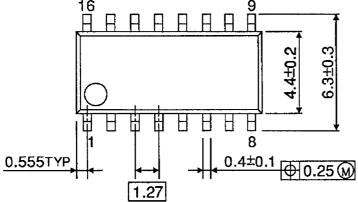
Weight: 1.11 g (Typ.)

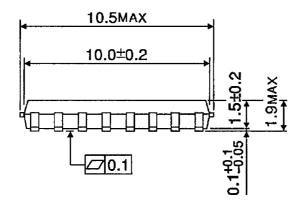
Unit: mm

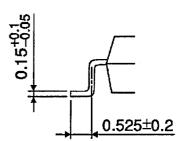
PACKAGE DIMENSIONS

SOP16-P-225-1.27









Weight: 0.16 g (Typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

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